NSN 5961-01-164-8398

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View Online at https://aerobasegroup.com/nsn/5961-01-164-8398 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.730 inches **Internal Configuration:** Field effect-dual gate Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-72 **Electrode Internally-electrically Connected To Case:** Gate **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 drain to source voltage **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current of standard range **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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